

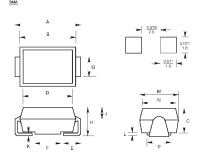
SRN3 THRU SRN7

SURFACE MOUNT FAST SWITCHNG RECTIFIER

Reverse Voltage - 50 to 600 Volts Forward Current - 1.0 Ampere

Features

- For surface mounted applications
- Low profile package
- Built-in strain relief
- Easy pick and place
- Fast recovery times for high efficiency
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- High temperature soldering: 260℃/10 seconds at terminals



Mechanical Data

• Case: SMA molded plastic

• Terminals: Solder plated solderable per

MIL-STD-750, method 2026

Polarity: Indicated by cathode band
Weight: 0.004 ounce, 0.113 gram

D IM E N S IO N S										
DIM	inches		m	Note						
	M in .	Max.	M in .	Max.	Note					
A	0.216	0.226	5 . 4 8	5 . 7 4						
В	0.176	0.182	4 . 4 8	4 . 6 3						
C	0.094	0.100	2 .4 0	2.55						
D	0.170	0.176	4.33	4 . 4 8						
E	0.039	0.055	1.00	1.40						
F	0.080	0.081	2.03	2.07						
G	0.068	0.083	1 .7 2	2.10						
Н	0.112	0.118	2.85	3.00						
J	0.057		1.44							
K		0.018		0.45						
L	0.016		0.40							
М	0.109	0.115	2 .7 7	2.93						
N	0.105	0.107	2 . 6 7	2.73						
P	0.078	0.081	2.00	2.05						

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	SRN3	SRN4	SRN5	SRN6	SRN7	Units
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	Volts
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	Volts
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	Volts
Maximum average forward rectified current at $\rm T_L = 90^{\circ}C$	I _(AV)		Amp				
Peak forward surge current 8.3mS single half sine-wave superimposed on rated load (MIL-STD-750D 4066 method)	I _{FSM}	30.0					Amps
Maximum instantaneous forward voltage at 1.0A	V _F	1.3					Volts
Maximum DC reverse current at rated DC blocking voltage T _A =125°C	I _R		μА				
Maximum reverse recovery time (Note 1) T _J =25°C	T _{rr}	150 250		250	500	nS	
Typical junction capacitance (Note 2)	C _J		ρF				
Maximum thermal resistance (Note 3)	R _{⊕JL}		°C/W				
Operating and storage temperature range	T _J , T _{STG}		°C				

Notes:

- (1) Reverse recovery test conditions: $I_F = 0.5A$, $I_R = 1.0A$, $I_{rr} = 0.25A$
- (2) Measured at 1.0MHz and applied reverse voltage of 4.0 volts
- (3) 8.0mm2 (0.013mm thick) land areas

RATINGS AND CHARACTERISTIC CURVES

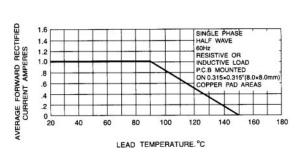


Fig. 1 - FORWARD CURRENT DERATING CURVE

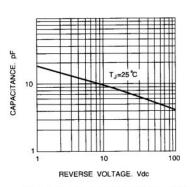


Fig. 2-TYPICAL JUNCTION CAPACITANCE

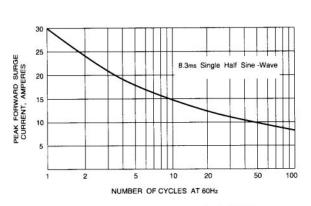


Fig. 3 - PEAK FORWARD SURGE CURRENT

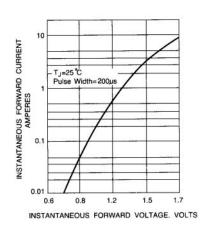
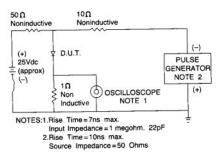


Fig. 4 - TYPICAL FORWARD CHARACTERISTICS



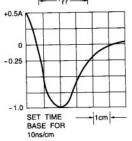


Fig. 5-REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM